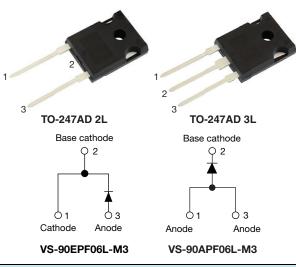
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VS-90EPF06L-M3, VS-90APF06L-M3

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# Fast Soft Recovery Rectifier Diode, 90 A



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	90 A			
V <sub>R</sub>	600 V			
V <sub>F</sub> at I <sub>F</sub>	1.3 V			
I <sub>FSM</sub>	1000 A			
t <sub>rr</sub>	70 ns			
T <sub>J</sub> max.	150 °C			
Package	TO-247AD 2L, TO-247AD 3L			
Circuit configuration	Single			
Snap factor	0.5			

#### FEATURES

- · Glass passivated pellet chip junction
- Low forward voltage drop and short reverse RoHS
  recovery time
  COMPLIANT
- Designed and qualified according to HALOGEN JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

### DESCRIPTION

The VS-90EPF006L-M3, VS-90APF006L-M3 soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
V <sub>RRM</sub>		600	V	
I <sub>F(AV)</sub>	Sinusoidal waveform	90	٨	
I <sub>FSM</sub>		1000	А	
t <sub>rr</sub>	1 A, -100 A/µs	70	ns	
V <sub>F</sub>	40 A, T <sub>J</sub> = 25 °C	1.12	V	
TJ	Range	-40 to +150	°C	

VOLTAGE RATINGS				
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 ℃ mA	
VS-90EPF06L-M3	600	700	17	
VS-90APF06L-M3	600	700	17	



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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 108 °C, 180° con	duction half sine wave	90	
Maximum peak one cycle	I	10 ms sine pulse, rate	d V <sub>RRM</sub> applied	850	А
non-repetitive surge current	I <sub>FSM</sub>	10 ms sine pulse, no v	oltage reapplied	1000	
Maximum 12t for fusing	l <sup>2</sup> t	10 ms sine pulse, rate	d V <sub>RRM</sub> applied	3610	A <sup>2</sup> s
Maximum I <sup>2</sup> t for fusing I <sup>2</sup> t		10 ms sine pulse, no v	10 ms sine pulse, no voltage reapplied		A-S
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied		51 000	A²√s
ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V <sub>FM</sub>	90 A, T <sub>J</sub> = 25 °C		1.3	V
Forward slope resistance	r <sub>t</sub>	T <sub>J</sub> = 150 °C		3.5	mΩ
Threshold voltage	V <sub>F(TO)</sub>			0.85	V
Maximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 25 °C	$V_{B} = rated V_{BBM}$	0.1	mA
		T <sub>J</sub> = 150 °C	$v_{\rm R}$ = rated $v_{\rm RRM}$	17	ША

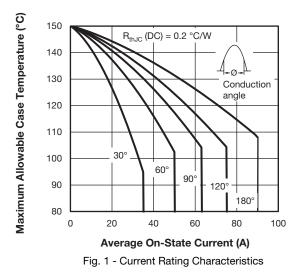
RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t <sub>rr</sub>	In at 40 Ank	190	ns	I <sub>FM</sub> t
Reverse recovery current	I <sub>rr</sub>	I <sub>F</sub> at 40 A <sub>pk</sub> 25 A/μs	3.4	А	
Reverse recovery charge	Q <sub>rr</sub>	25 °C	0.5	μC	
Snap factor	S		0.5		I IRM(REC)

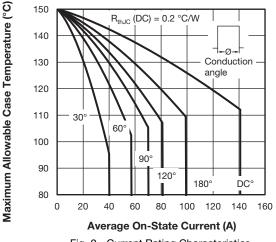
THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation	0.2	
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		40	°C/W
Typical thermal resista case to heatsink	ance,	R <sub>thCS</sub>	Mounting surface, smooth, and greased	0.25	
Approximate weight				6	g
				0.21	oz.
minimum				6 (5)	kgf ⋅ cm
Mounting torque max	maximum			12 (10)	(lbf ⋅ in)
Marking device			Case style TO-247AD 2L	90EP	F06L
			Case style TO-247AD 3L	90AP	F06L



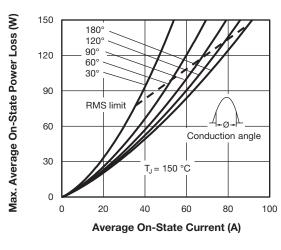
# VS-90EPF06L-M3, VS-90APF06L-M3

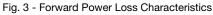
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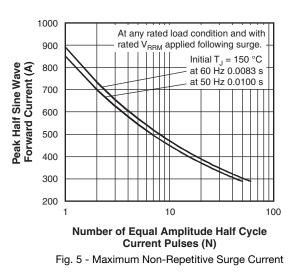






Max. Average On-State Power Loss (W) 200 180 180 120 160 90° DC 60° 140 30° 120 100 RMS limit 80 60 Conduction angle 40  $T_J = 150 \ ^\circ C$ 20 0 0 30 60 90 120 150 Average On-State Current (A)

Fig. 4 - Forward Power Loss Characteristics



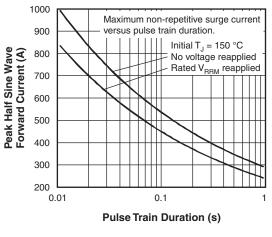


Fig. 6 - Maximum Non-Repetitive Surge Current

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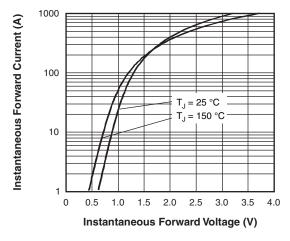


Fig. 7 - Forward Voltage Drop Characteristics

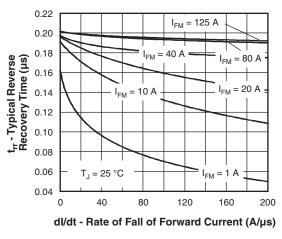


Fig. 8 - Recovery Time Characteristics,  $T_J$  = 25  $^\circ\text{C}$ 

= 80 A

 $I_{FM} = 10 \text{ A}$ 

I<sub>FM</sub> = 1 A

200

160

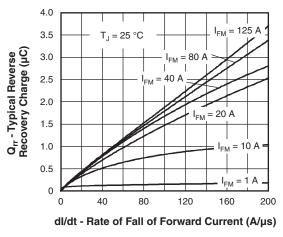
I<sub>FM</sub>

= 20 A

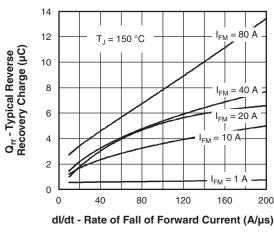
40 A

120

FM









dl/dt - Rate of Fall of Forward Current (A/µs)

80

Fig. 9 - Recovery Time Characteristics,  $T_{J}$  = 150  $^{\circ}\text{C}$ 

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0.6

0.5

0.4

0.3

0.2

0.1

0

0

T<sub>.1</sub> = 150 °C

40

t<sub>tr</sub> - Typical Reverse Recovery Time (μs)

4

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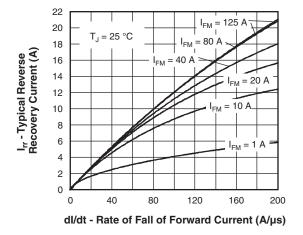


Fig. 12 - Recovery Current Characteristics,  $T_J = 25 \ ^{\circ}C$ 

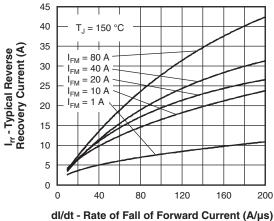


Fig. 13 - Recovery Current Characteristics,  $T_J = 150 \ ^\circ C$ 

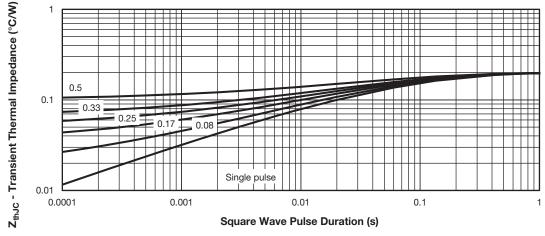
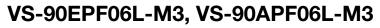


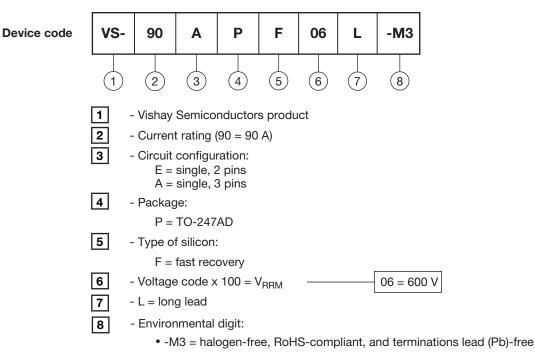
Fig. 14 - Thermal Impedance Z<sub>thJC</sub> Characteristics



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### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER TUBES	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-90EPF06L-M3	25	500	Antistatic plastic tubes		
VS-90APF06L-M3	25	500	Antistatic plastic tubes		

LINKS TO RELATED DOCUMENTS				
Dimensions	TO-247AD 2L	www.vishay.com/doc?95536		
Differisions	TO-247AD 3L	www.vishay.com/doc?95626		
Port marking information	TO-247AD 2L	www.vishay.com/doc?95648		
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007		



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